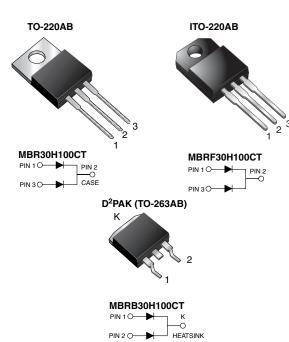
Vishay General Semiconductor

HALOGEN

FREE

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V_{RRM}	100 V					
I _{FSM}	275 A					
V_{F}	0.67 V					
I _R	5.0 μA					
T_J max.	175 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)					
Circuit configuration Common cathode						

FEATURES

- Power pack
- · Guardring for overvoltage protection
- · Low power loss, high efficiency
- Low forward voltage drop
- · Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/N-M3 - RoHS-compliant, Halogen free, commercial grade

grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)						
PARAMETER			MBR30H100CT MBRF30H100CT MBRB30H100CT	UNIT		
Maximum repetitive peak reverse voltage			100	V		
Working peak reverse voltage			100			
Maximum DC blocking voltage			100			
Maximum average forward rectified current	total device	I _{F(AV)}	30			
(fig.1)	per diode		15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			275	Α		
Peak repetitive reverse surge current per diode at $t_p = 2.0~\mu s$, 1 kHz		I _{RRM}	1.0			
Voltage rate of change (rated V _R)			10 000	V/µs		
Operating junction and storage temperature range			-65 to +175	°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min		V_{AC}	1500	V		



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ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
		I _F = 15 A	T _J = 25 °C	0.82	- V	
Maximum instantaneous forward voltage per diede	V _F (1)	I _F = 15 A	T _J = 125 °C	0.67		
Maximum instantaneous forward voltage per diode		I _F = 30 A	T _J = 25 °C	0.93		
		I _F = 30 A	T _J = 125 °C	0.80		
Maximum reverse current per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	5.0	μΑ	
Maximum reverse current per diode			T _J = 125 °C	6.0	mA	

Note

 $^{(1)}$ Pulse test: 300 μ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width, ≤ 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR30H100CT	MBRF30H100CT	MBR30H100CT	UNIT	
Typical thermal resistance per diode	$R_{\theta JC}$	1.9	4.6	1.9	°C/W	

ORDERING INFORMATION								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	MBR30H100CT-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	MBRF30H100CT-E3/45	1.99	45	50/tube	Tube			
D ² PAK (TO-263AB)	MBRB30H100CT-M3/I	1.35	I	800/reel	Tape and reel			

RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

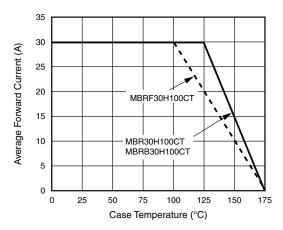


Fig. 1 - Forward Derating Curve Per Diode

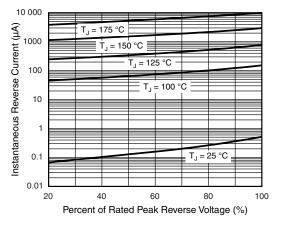


Fig. 4 - Typical Reverse Characteristics Per Diode

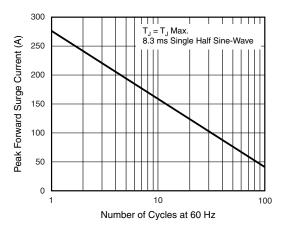


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

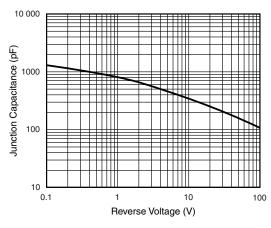


Fig. 5 - Typical Junction Capacitance Per Diode

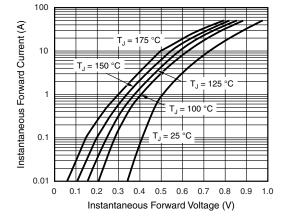


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

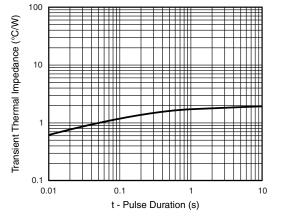
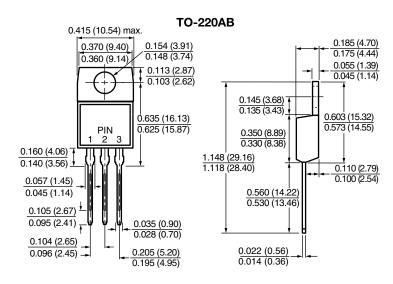


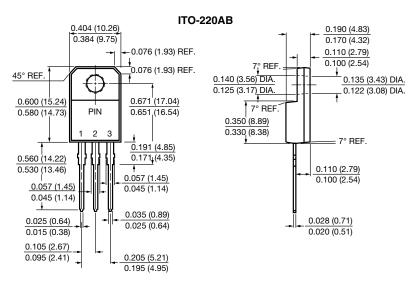
Fig. 6 - Typical Transient Thermal Impedance Per Diode



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

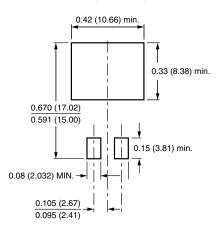




D²PAK (TO-263AB)

0.411 (10.45) 0.190 (4.83) 0.380 (9.65) 0.160 (4.06) 0.055 (1.40) 0.245 (6.22) 0.045 (1.14) MIN. 0.055 (1.40) 0.360 (9.14) 0.047 (1.19) 0.320 (8.13) 0.624 (15.85) 0.591 (15.00) Κ 2 т 0 to 0.01 (0 to 0.254) 0.110 (2.79) 0.110 (2.72) 0.037 (0.940) 0.021 (0.53) 0.027 (0.686) 0.014 (0.36) 0.105 (2.67) 0.140 (3.56) 0.095 (2.41) 0.205 (5.20) 0.110 (2.79) 0.195 (4.95)

Mounting Pad Layout





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